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July 2008

FDW2501NZ

AIRCHIL

Dual N-Channel 2.5V Specified PowerTrench® MOSFET

General Description

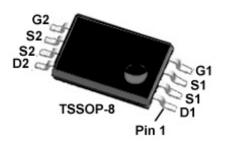
This N-Channel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

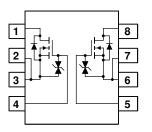
Applications

- · Load switch
- Motor drive
- DC/DC conversion
- Power management

Features

- 5.5 A, 20 V. $R_{DS(ON)} = 18 \ m\Omega \ @V_{GS} = 4.5V$ $R_{DS(ON)} = 25 \ m\Omega \ @V_{GS} = 2.5V$
- Extended V_{GSS} range (±12V) for battery applications
- ESD protection diode (note 3)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- Low profile TSSOP-8 package





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		20	V
V _{GSS}	Gate-Source Voltage		±12	V
I _D	Drain Current – Continuous	(Note 1a)	5.5	А
	– Pulsed		30	
P _D	Power Dissipation	(Note 1a)	1.0	W
		(Note 1b)	0.6	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C
Therma	I Characteristics	<u>.</u>		
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	100	°C/W
		(Note 1b)	125	

Package Marking and Ordering Information

 Device Marking	Device	Reel Size	Tape width	Quantity
2501NZ	FDW2501NZ	13"	12mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Char	acteristics			J	J	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	20			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		14		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 16 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			10	μA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -12 \ V, V_{DS} = 0 \ V$			-10	μA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	0.6	1.0	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 4.5 \; V, \ \ I_D = 5.5 \; A \\ V_{GS} = 2.5 \; V, \ \ I_D = 5 \; A \\ V_{GS} = 4.5 \; V, \; I_D = 5.5 \; A, \; T_J \!=\! 125^\circ \! C \end{array} $		14 19 19	18 25 29	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = 4.5 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	30			Α
g _{FS}	Forward Transconductance	$V_{DS} = 5 V$, $I_{D} = 5.5 A$		30		S
Dvnamio	Characteristics	·		•	•	•
C _{iss}	Input Capacitance	$V_{DS} = 10 V$, $V_{GS} = 0 V$,		1286		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		305		pF
C _{rss}	Reverse Transfer Capacitance	7		161		pF
Switchir	g Characteristics (Note 2)	·	•	•	•	•
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 10 V$, $I_D = 1 A$,		10	20	ns
tr	Turn–On Rise Time	$V_{GS} = 4.5 V$, $R_{GEN} = 6 \Omega$		14	25	ns
d(off)	Turn–Off Delay Time	-		25	40	ns
t _f	Turn–Off Fall Time			8	16	ns
Qg	Total Gate Charge	$V_{DS} = 10 V$, $I_{D} = 5.5 A$,		12	17	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 4.5 V$		2.6		nC
Q _{gd}	Gate-Drain Charge	1		3		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
I _s	Maximum Continuous Drain–Source				1.0	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = 1.0 A$ (Note 2)		0.7	1.2	V

 R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BJC} is guaranteed by design while R_{BCA} is determined by the user's board design.

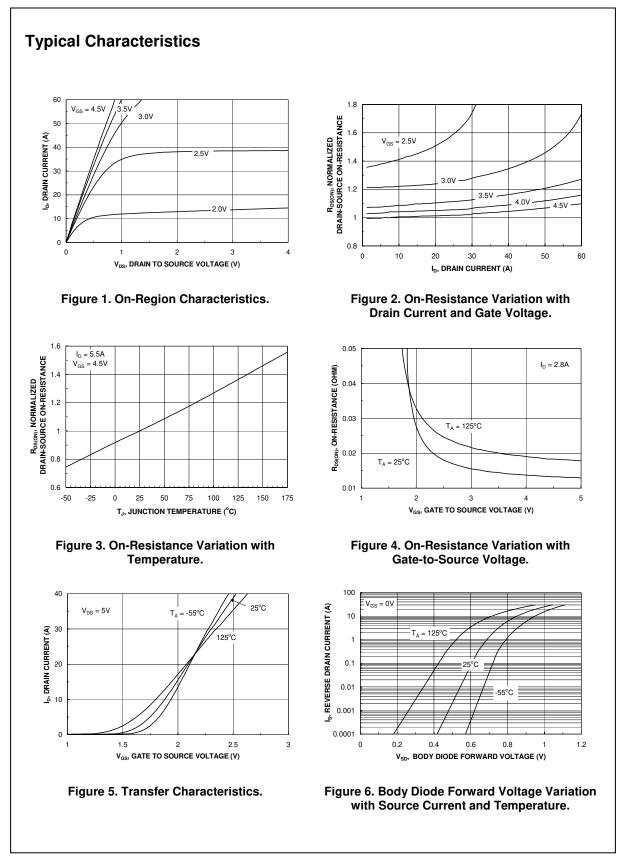
a) $\rm R_{\rm 6JA}$ is 100°C/W (steady state) when mounted on a 1 inch² copper pad on FR-4.

b) $R_{\theta JA}$ is 125°C/W (steady state) when mounted on a minimum copper pad on FR-4.

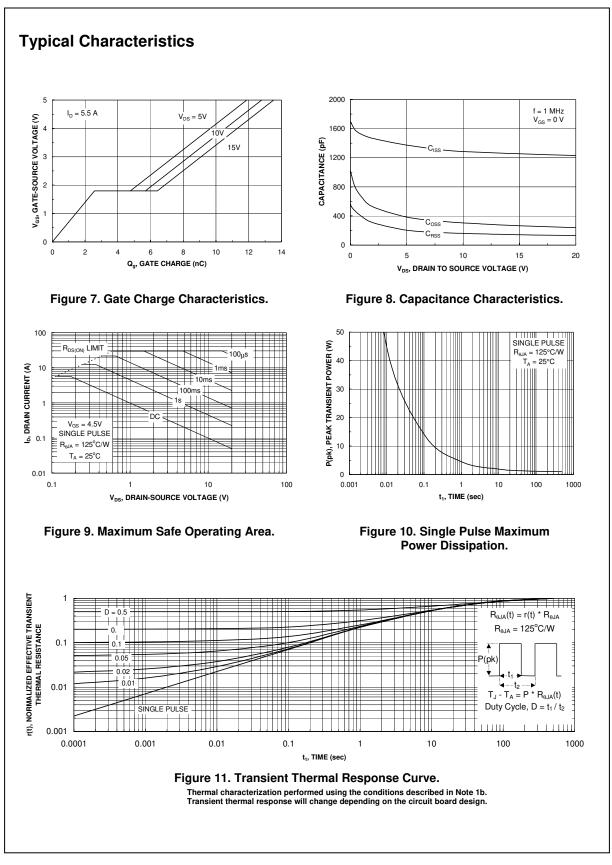
2. Pulse Test: Pulse Width < 300μ s, Duty Cycle < 2.0%

3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

FDW2501NZ



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